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Ferroelectric and Dielectric Investigations of Bismuth Ferrite (BiFeO₃) Nanoceramics

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ABSTRACT

In this paper we report the synthesis of BiFeO₃ ceramics by solid state reaction method. The X-ray analysis depicts the BiFeO₃ sample have rhombohedral perovskite structure. The ferroelectric measurement shows BiFeO₃ ceramic exhibits ferroelectric nature with saturation, remnant polarizations of $P_s = 0.26 \mu\text{C}/\text{cm}^2$, $P_r = 0.11 \mu\text{C}/\text{cm}^2$ respectively. The dielectric constant and loss as a function of temperature (30-325°C) in the frequency range 10 kHz-1MHz shows that the dielectric constant and loss increases with increasing temperature. The room temperature dielectric measurement with frequency reveals the dielectric constant and loss decreases with increasing frequency for BiFeO₃ ceramics.

Keywords: BiFeO₃ Ceramics, Solid State Reaction, Characterizations, Measurements.

INTRODUCTION

Multiferroic materials possess simultaneous existence of electric and magnetic nature together in a single phase [1-2]. These multiferroics have potential applications in information storage [3], microelectronics [4], memories, spintronic, magnetoelectric sensor devices [5], multiple state memory devices [6] and magnetoelectronics [7]. In this novel class of materials, there exists a strong coupling between magnetic and electric order parameters which results into the co-existence of ferromagnetism and ferroelectricity in a single phase, results in the production of magnetoelectric effect in the material. In ME effect a polarization can be induced by application of magnetic field and magnetization can be induced by application of electric field [8]. These materials have potential applications for many devices from the technological point of view. BiFeO₃ have ferroelectric Curie temperature $T_c = 830^{\circ}\text{C}$ and antiferromagnetic Neel temperature $T_N = 370^{\circ}\text{C}$ [9].

The objective of this work to determine the ferroelectric and dielectric properties of BiFeO₃ ceramics synthesized by a simple solid state reaction.

MATERIALS AND METHODS

2.1 Synthesis of BiFeO₃

The BiFeO₃ sample was prepared by a standard solid state reaction using Bi₂O₃ (Hi-Media Chemical, India), Fe₂O₃ (Sigma Aldrich) as a starting materials. Firstly the Bi₂O₃ and Fe₂O₃ in stoichiometric ratios were thoroughly mixed in a stoichiometric ratios and Ball milled for 24 hrs. The mixture was calcined at 650⁰ C for 1hr and then powder was ground and cold pressed into pellets and sintered at 700⁰ C for 1 hour. Finally these pellets were carried out for further characterizations and measurements.

2.2 Characterizations

The sintered pellets were characterized by x-ray diffraction (XRD) using CuK α radiation ($\lambda=1.54178$) (Philips X-pert PRO) for phase identification in the 2 θ range (20-60⁰). The surface morphological studies were addressed by using SEM (EVO-50). Dielectric measurement was performed on H.P. Impedance analyzer (4192A LF) in the frequency range of 10 kHz to 1 MHz with variable temperature range from 30 - 400 ⁰C and the dielectric constant as a function of frequency measurement was carried out by Precision Impedance analyzer (Agilent 4294 A) at room temperature. The ferroelectric measurement was carried at room temperature on ferroelectric tester (Radiant Precision Premier II Technology) at 10 Hz. All measurement were carried on a sintered pellets polished with a thin layer of silver paste fired at 350⁰ C for 30 min. The silver layer act as an electrode.

RESULTS AND DISCUSSION

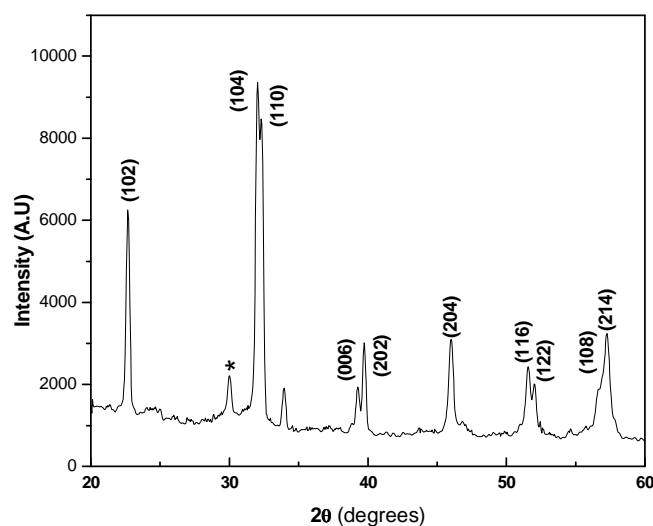


Fig.1. XRD spectra of BiFeO₃ [* Bi₂Fe₄O₉/Bi₂O₃]

3.1 Structural Studies:

Fig.1. shows the XRD pattern of BiFeO_3 at RT. The XRD results showed that the BiFeO_3 have rhombohedral perovskite structure with space group $R3c$. Typical results shows good agreement with the reported data with an additional secondary phase corresponding to $\text{Bi}_2\text{Fe}_4\text{O}_9/\text{Bi}_2\text{O}_3$ has been appearing around 30° in 2θ range marked by stars. The average crystallite size was found to about 60 nm.

3.2 Surface Morphology:

Fig. 2 shows the surface morphological characteristics of BiFeO_3 . The grains are non-uniform, agglomerated and less densified with interconnected structure.

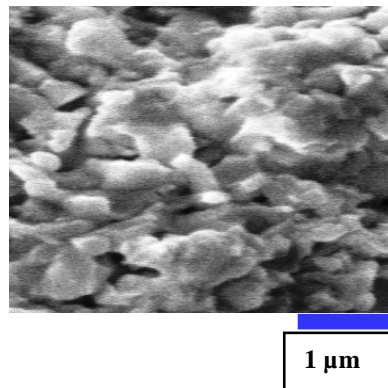


Fig. 2 Surface morphology of BiFeO_3 ceramic

3.3 Ferroelectric P-E loop:

Fig.3. shows the room temperature P-E hysteresis loop of BiFeO_3 sample sintered at 700°C for 1 hour and exhibit ferroelectric nature. The loop shows proper saturation with enhanced saturation polarization (P_s), remnant polarization (P_r) and coercive electric field (E_c). The saturation polarization (P_s), remnant polarization (P_r) and coercive electric field (E_c) are $P_s = 0.26 \mu\text{C}/\text{cm}^2$, $P_r = 0.11 \mu\text{C}/\text{cm}^2$ and $E_c = 3.2 \text{ kV}/\text{cm}$.

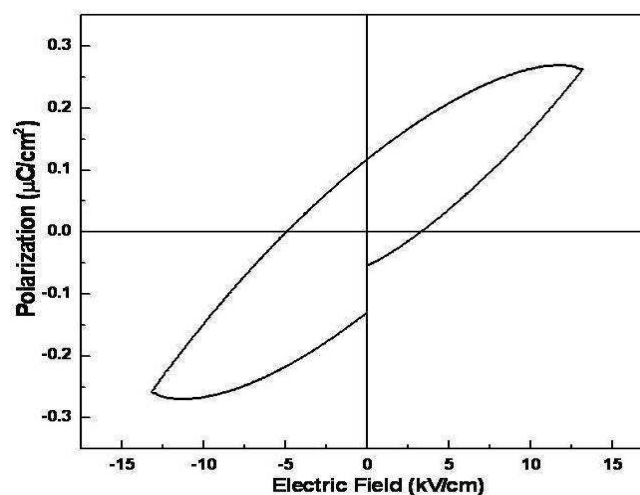


Fig.3. P-E Hysteresis loop of BiFeO_3

3.4 Dielectric Constant-Temperature Measurement

Fig.4. shows a dielectric constant versus temperature measurement for BiFeO₃ sample in the temperature range 30 – 325 °C with the frequency range 10 kHz-1MHz. The dielectric constant shows a continuous increase with increasing temperature. The measured values of permittivity were $\epsilon \sim 2542$, $T=325^\circ\text{C}$ and $\epsilon \sim 156$ at room temperature for 10 kHz in BiFeO₃ ceramic.

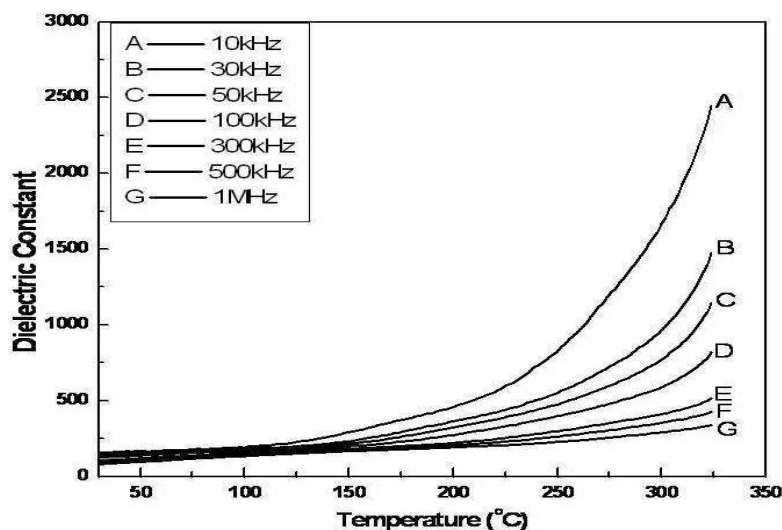


Fig.4. ϵ -T (f = Constant) of BiFeO₃ Sample

3.5 Dielectric loss-Temperature Measurement

Fig.5. shows a dielectric loss versus temperature plot of BiFeO₃ samples in the temperature range 30 – 325 °C at frequency range 10 kHz-1MHz. The dielectric loss exhibits a continuous increase with increasing temperature. The small values of dielectric loss was $\tan\delta \sim 0.29$, $f = 10 \text{ kHz}$ at room temperature and $\tan\delta \sim 0.001$, $f = 1 \text{ MHz}$ at temperature $T = 400^\circ\text{C}$ for BiFeO₃.

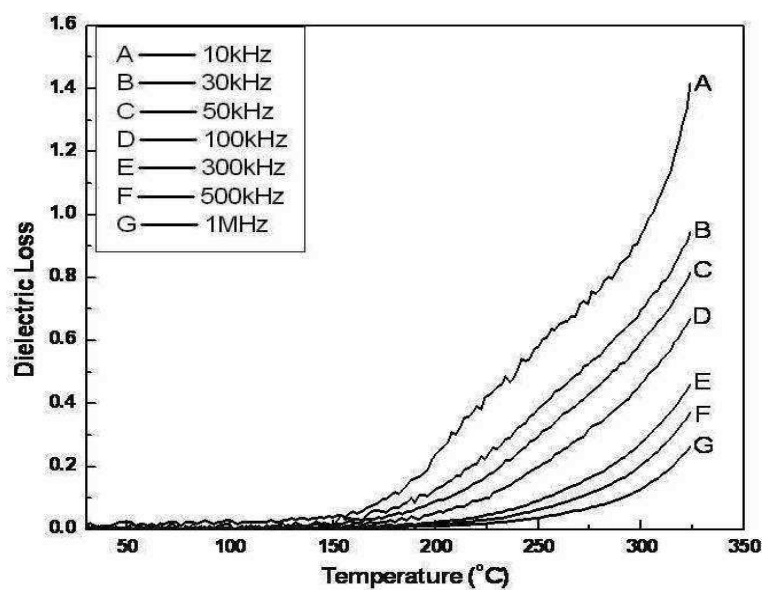


Fig.5. ϵ - $\tan\delta$ (f = Constant) of BiFeO₃ Sample

3.5. Dielectric Constant- Frequency Measurement:

Fig.6 (a) shows variation of dielectric constant versus frequency obtained for BiFeO₃ sample at room temperature in the frequency range 10 kHz -1 MHz shows the dielectric constant decreases with increasing frequency.

Fig.6 (b) shows variation of dielectric loss versus frequency obtained for BiFeO₃ sample at room temperature in the frequency range 10 kHz -1 MHz shows the dielectric loss decreases with increasing frequency.

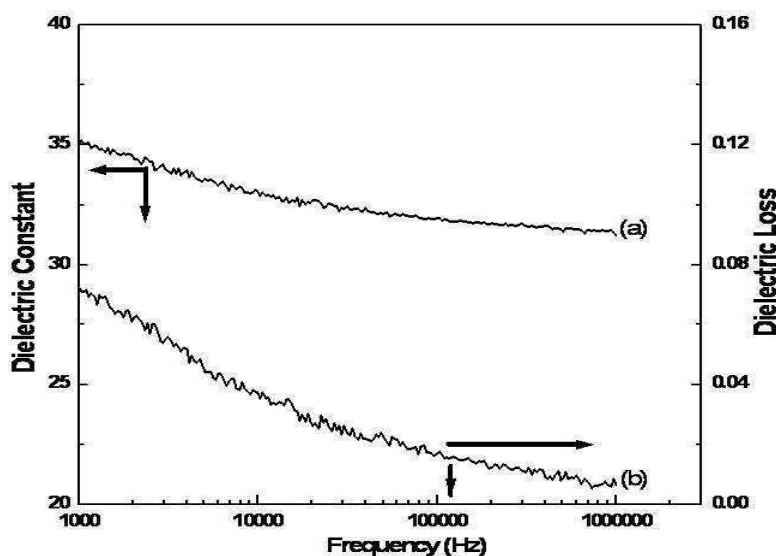


Fig.6 (a) ϵ -f (RT) plot and Fig. 6 (b) $\tan\delta$ -f (RT) plot of BiFeO₃ ceramic

CONCLUSION

The solid state synthesized BiFeO₃ ceramics shows the rhombohedral perovskite structure. The ferroelectric measurement reveals the ferroelectric nature of BiFeO₃ with saturation, remnant polarizations of $P_s = 0.26 \mu\text{C}/\text{cm}^2$, $P_r = 0.11 \mu\text{C}/\text{cm}^2$ respectively. The dielectric constant and loss as a function of temperature shows the dielectric constant and loss increases with increasing temperature. The room temperature dielectric measurement with frequency reveals the dielectric constant and loss decreases with increasing frequency for BiFeO₃ ceramics.

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